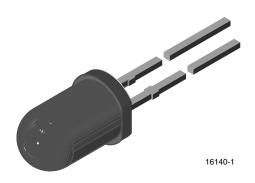
HALOGEN FREE

GREEN



Vishay Semiconductors

Silicon PIN Photodiode



DESCRIPTION

BPV10NF is a PIN photodiode with high speed and high radiant sensitivity in black, T-1¾ plastic package with daylight blocking filter. Filter bandwidth is matched with 850 nm to 950 nm IR emitters.

FEATURES

Package type: leadedPackage form: T-1¾

• Dimensions (in mm): Ø 5

- · Leads with stand-off
- High radiant sensitivity
- Daylight blocking filter matched with 850 nm to 950 nm emitters
- Fast response times
- Angle of half sensitivity: . = ± 20°
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>



- High speed detector for infrared radiation
- Infrared remote control and free air data transmission systems, e.g. in combination with TSFFxxxx series IR emitters

PRODUCT SUMMARY				
COMPONENT	I_{ra} (μA) at E _e = 1.0 mW/cm ² , λ = 940 nm, V_R = 5.0 V	φ (°)	λ _{0.5} (nm)	
BPV10NF	60	± 20	780 to 1050	

Note

· Test condition see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
BPV10NF	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		
BPV10NF-CS21	Reel	MOQ: 5000 pcs, 1000 pcs/reel	T-1		

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V_{R}	60	V	
Power dissipation	T _{amb} ≤ 25 °C	P _V	215	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	-40 to +100	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	t ≤ 5 s, 2 mm from body	T _{sd}	260	°C	
Thermal resistance junction to ambient	Connected with Cu wire, 0.14 mm ²	R _{thJA}	350	K/W	

ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



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BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 50 mA	V _F	-	0.85	1.3	V
Breakdown voltage	I _R = 100 μA, E = 0	V _(BR)	60	-	-	V
Reverse dark current	V _R = 20 V, E = 0	I _{ro}	-	1	5	nA
Diode capacitance	V _R = 0 V, f = 1 MHz, E = 0	C _D	-	11	-	pF
Open circuit voltage	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 850 \text{ nm}$	V _O	=	410	-	mV
Short circuit current	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 870 \text{ nm}$	I _K	-	50	-	μA
Reverse light current	$E_e = 1$ mW/cm ² , $\lambda = 870$ nm, $V_R = 5$ V	I _{ra}	-	55	-	μA
	$E_e = 1 \text{ mW/cm}^2, \lambda = 940 \text{ nm}, V_R = 5 \text{ V}$	I _{ra}	30	60	-	μA
Temperature coefficient of I _{ra}	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 870 \text{ nm}$, $V_R = 5 \text{ V}$	TK _{Ira}	-	-0.1	-	%/K
Absolute spectral sensitivity	$V_R = 5 \text{ V}, \ \lambda = 870 \text{ nm}$	s(λ)	-	0.55	-	A/W
Angle of half sensitivity		φ	=	± 20	-	0
Wavelength of peak sensitivity		λ_p	-	940	-	nm
Range of spectral bandwidth		λ _{0.5}	-	780 to 1050	-	nm
Quantum efficiency	λ = 950 nm	η	-	70	-	%
Noise equivalent power	V _R = 20 V, λ = 950 nm	NEP	-	3 x 10 ⁻¹⁴	-	W/√Hz
Detectivity	V _R = 20 V, λ = 950 nm	D	-	3 x 10 ¹²	-	cm√Hz/W
Rise time	V_R = 10 V, R_L = 50 Ω , λ = 830 nm	t _r	-	80	-	ns
Fall time	V_R = 10 V, R_L = 50 Ω , λ = 830 nm	t _f	-	60	-	ns

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

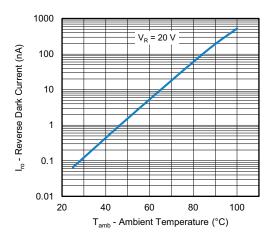


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

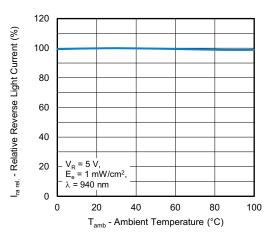


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

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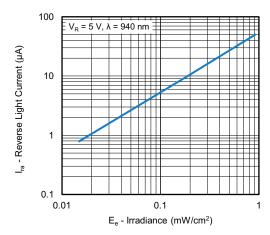


Fig. 3 - Reverse Light Current vs. Irradiance

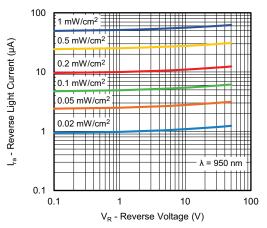


Fig. 4 - Reverse Light Current vs. Reverse Voltage

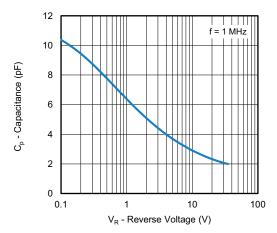


Fig. 5 - Diode Capacitance vs. Reverse Voltage

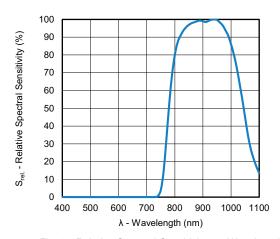


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

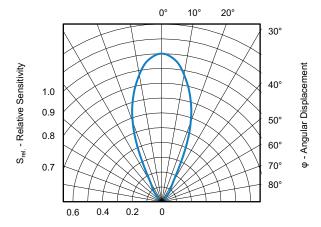
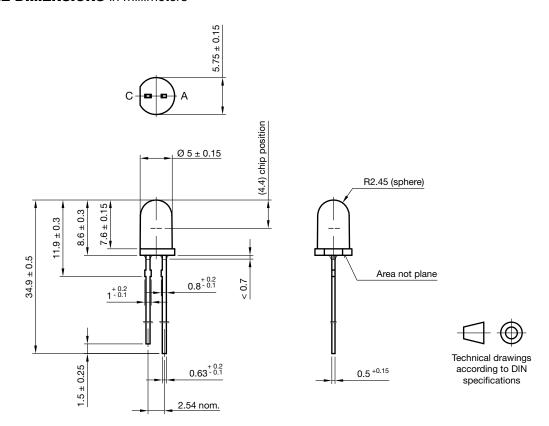


Fig. 7 - Relative Sensitivity vs. Angular Displacement

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PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.544-5185.01-4

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